

Outline

- Motivation
- Introduction to neural network model
- Knowledge-based NN model
 - Training with inductive bias
 - Building prior knowledge from multiple tasks
- End-to-end autonomous technology development

Goal:

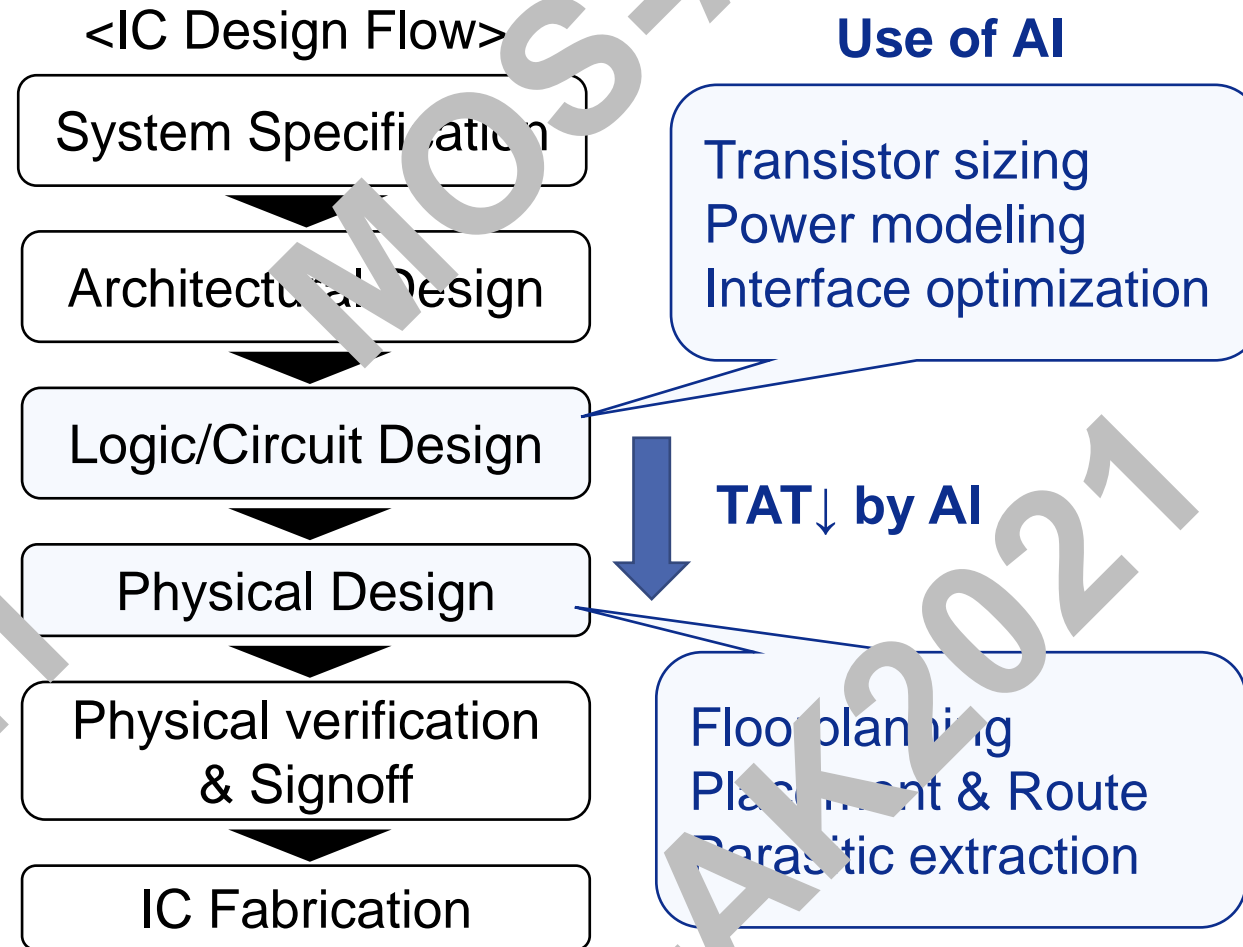
1. Provide understanding of neural network device modeling
2. Share possible directions to make NN device modeling more intelligent

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AI in IC Design

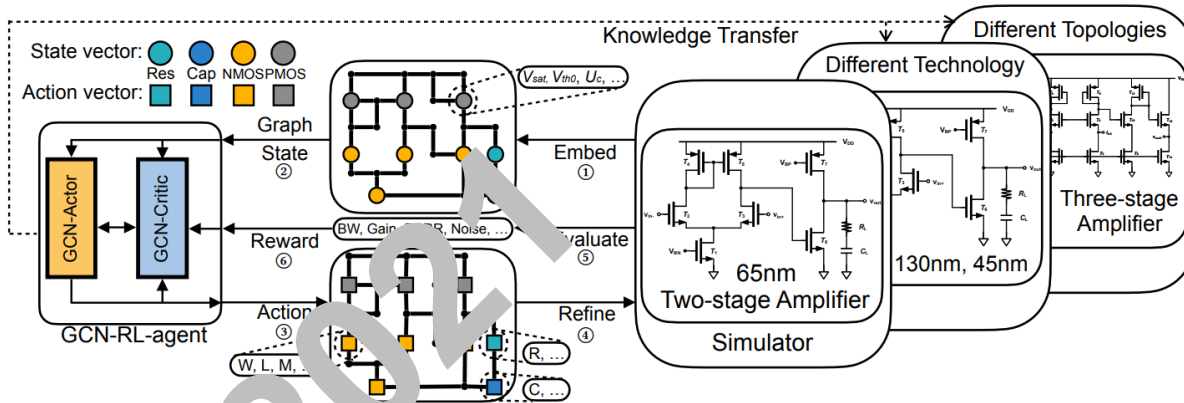
- Active research in hardware design optimization with AI



AI in IC Design - Examples

[Transistor Sizing]

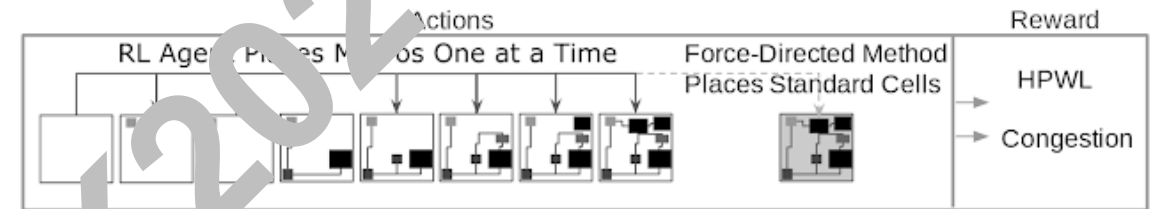
- Transferable transistor sizing with AI
 - Automated transistor sizing based on circuit performance results
 - Transfer knowledge of one technology/topology to another technology/topology



[H. Wang et al., "GCN-based circuit designer: Transferable transistor sizing with graph neural network and reinforcement learning," DAC, 2020]

[Floorplanning]

- Next generation Google AI accelerator designed using AI
 - "In under six hours, our method automatically generates chip floorplans that are superior or comparable to those produced by humans in all key metrics, including power consumption, performance, and chip area."

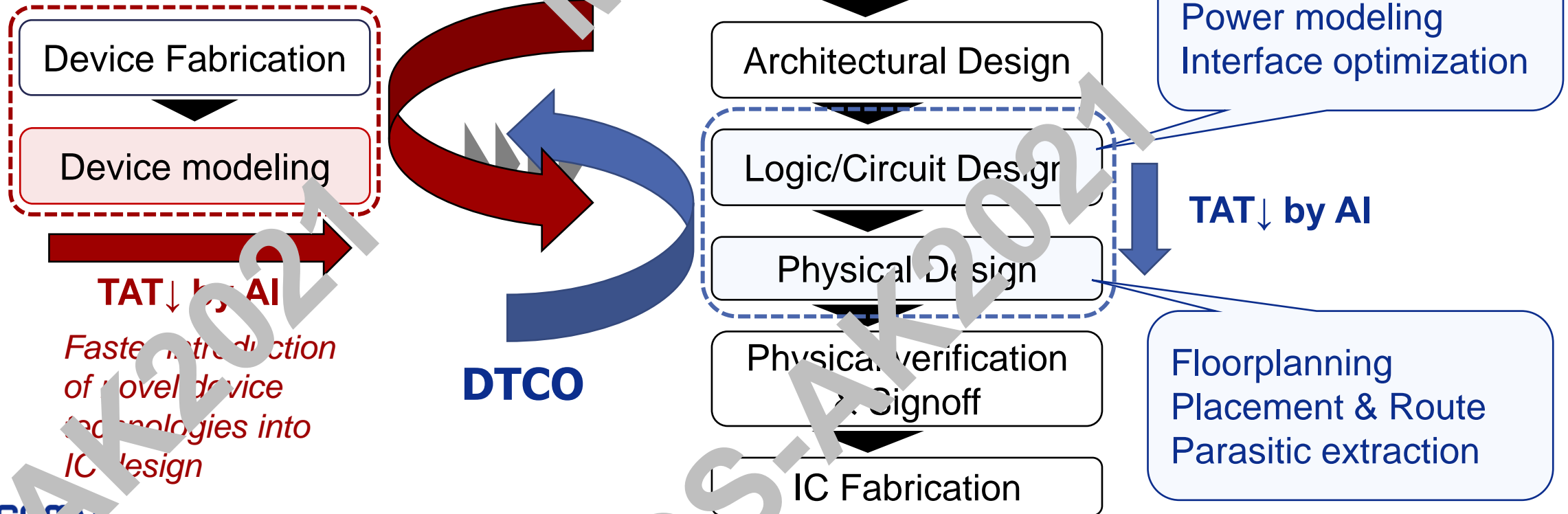


[<http://ai.googleblog.com/2020/04/chip-design-with-deep-reinforcement.html>]

[M. Hoseini et al., "A graph placement methodology for fast chip design," Nature, 2021]

AI in Device Modeling

- Limited research in device modeling using AI
- DTCO facilitated by AI in device modeling
Design Technology Co-optimization

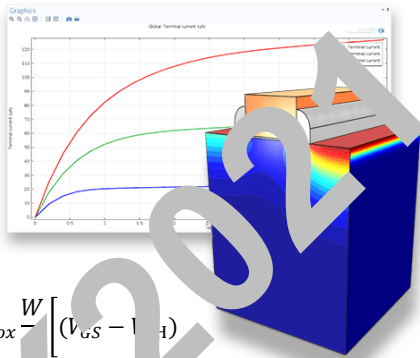


Conventional device modeling: Analytical model

- Physics-based analytical model: Long development time, limited accuracy

Device analysis & Analytical model development

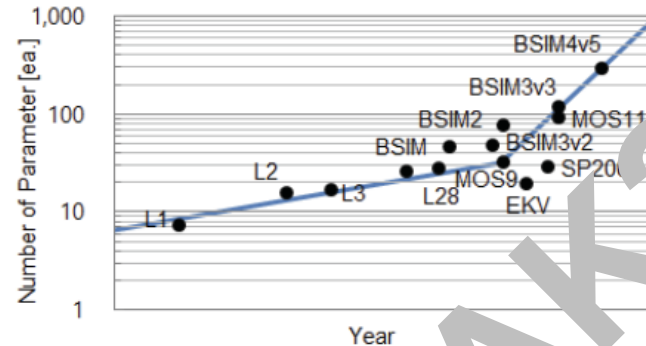
- Development time: years
- Include known physics + fitting parameters
- Need semiconductor experts



$$I_{D,tri} = \mu_p C_{ox} \frac{W}{L} \left[(V_{GS} - V_{th}) - \frac{V_{DS}}{2} \right] \left[V_{GS} - V_{th} - \lambda(V_{DS} - V_{D,sat}) \right]$$

Parameter extraction

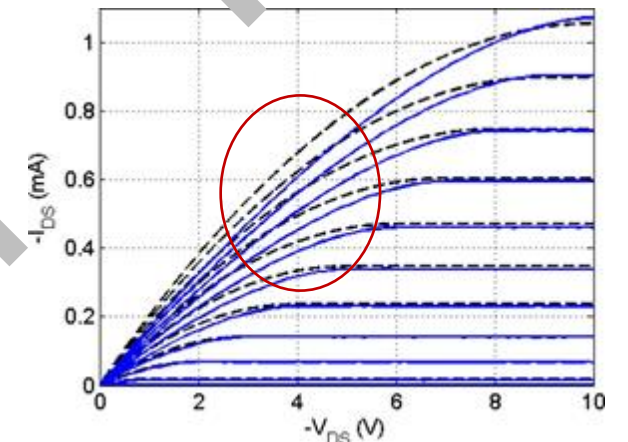
- Development time: months – reduced to hours by using AI [Primarus SDEP]
- Hundreds of parameters to fit



[Y. Kim *et al.*, "The efficient DTCO Compact Modeling Solutions to Improve EDC and Reduce TAT," SISPA 2018]

Analytical model

- Inaccuracy from unknown physics



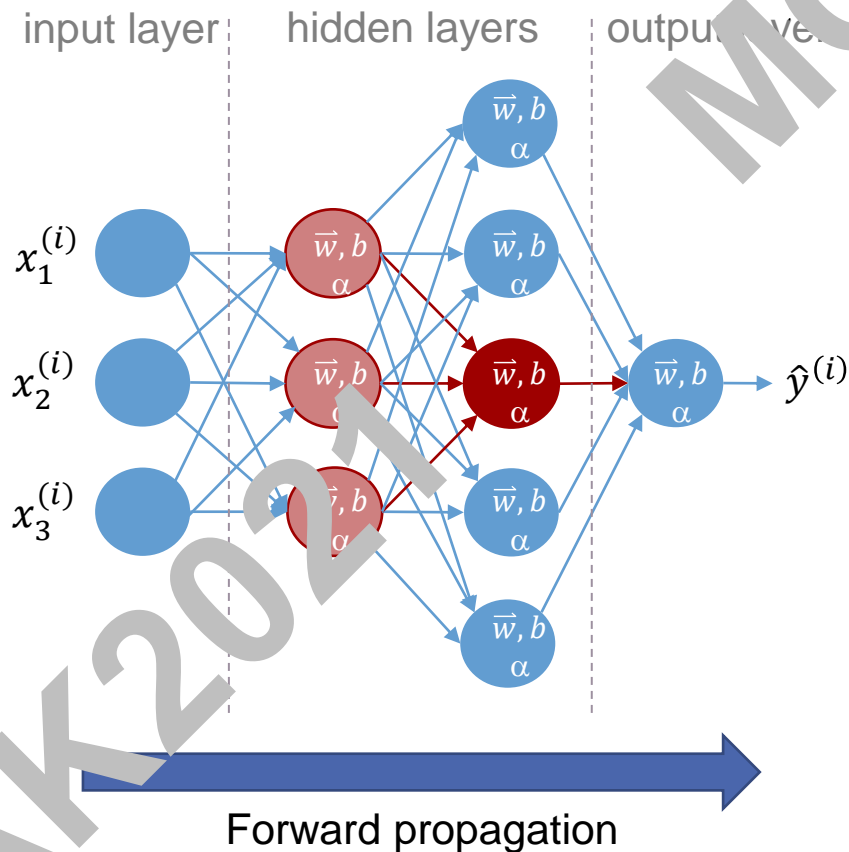
----- Measured ——— Model

Outline

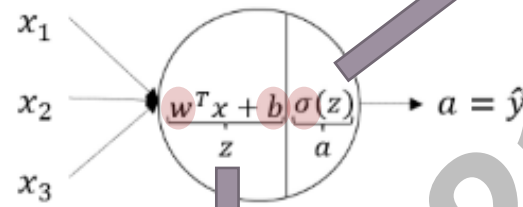
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Neural network basics – Forward propagation

- Data set: $\left(\begin{pmatrix} x_1^{(1)} \\ x_2^{(1)} \\ x_3^{(1)} \end{pmatrix}, y^{(1)} \right), \left(\begin{pmatrix} x_1^{(2)} \\ x_2^{(2)} \\ x_3^{(2)} \end{pmatrix}, y^{(2)} \right), \dots, \left(\begin{pmatrix} x_1^{(m)} \\ x_2^{(m)} \\ x_3^{(m)} \end{pmatrix}, y^{(m)} \right)$



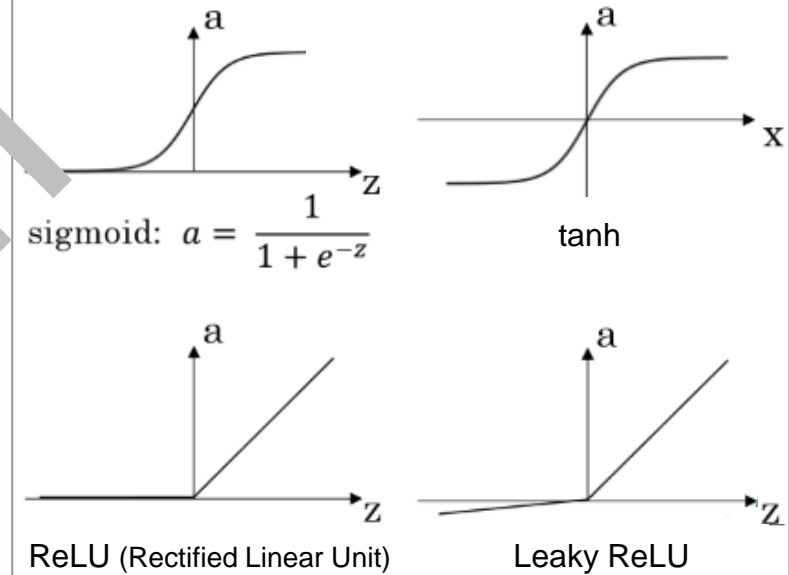
Each node:



weight $\begin{pmatrix} w_1 \\ w_2 \\ w_3 \end{pmatrix}$, bias b

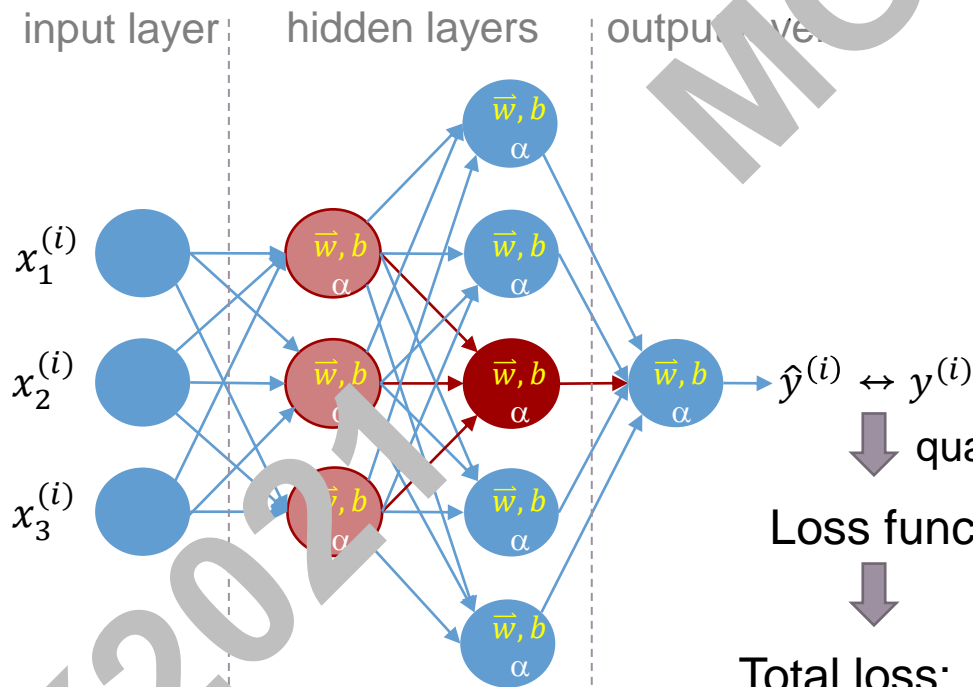
Linear combination of inputs

activation function σ
Factor that adds non-linearity



Neural network basics – Backward propagation

- Data set: $\left(\begin{pmatrix} x_1^{(1)} \\ x_2^{(1)} \\ x_3^{(1)} \end{pmatrix}, y^{(1)} \right), \left(\begin{pmatrix} x_1^{(2)} \\ x_2^{(2)} \\ x_3^{(2)} \end{pmatrix}, y^{(2)} \right), \dots, \left(\begin{pmatrix} x_1^{(m)} \\ x_2^{(m)} \\ x_3^{(m)} \end{pmatrix}, y^{(m)} \right)$



Backward propagation

quantify accuracy
 Loss function: $L(\hat{y}^{(i)}, y^{(i)})$

Total loss: $J = \frac{1}{m} \sum_{i=1}^m L(\hat{y}^{(i)}, y^{(i)})$

Update \bar{w}, b of each node to minimize J

At each node,

$$w_1 := w_1 - \alpha \cdot dw_1$$

$$w_2 := w_2 - \alpha \cdot dw_2$$

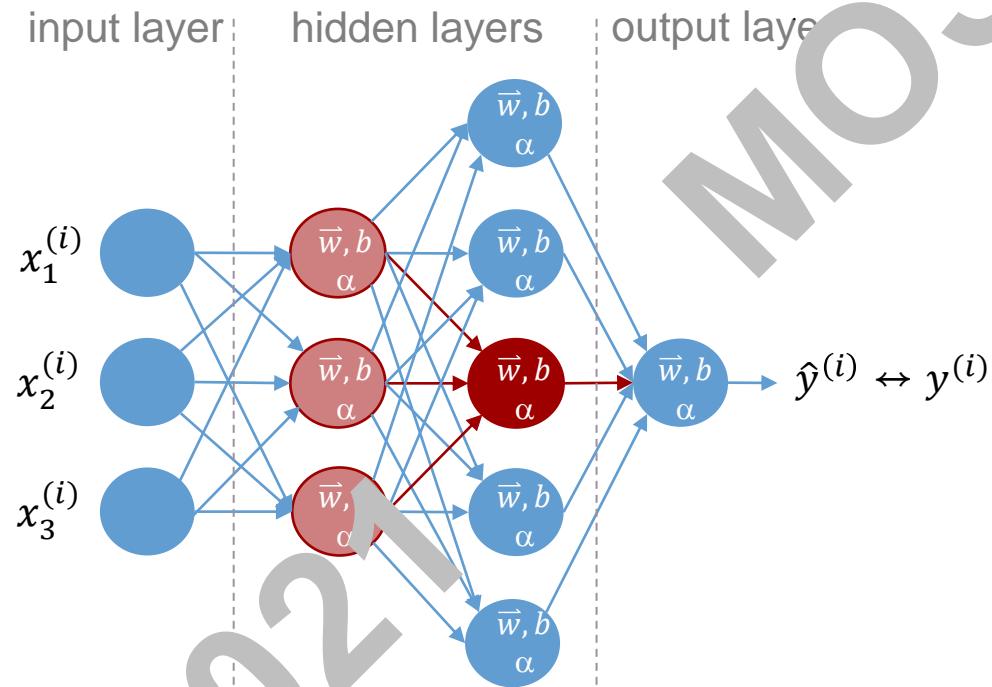
$$w_3 := w_3 - \alpha \cdot dw_3$$

$$b := b - \alpha \cdot db$$

learning rate α :
 determines
 magnitude of
 change

Neural network basics - Training

- Repeat forward & back propagation until desired accuracy is reached
 - fix weight & bias - **Arbitrary function can be expressed based on user data**

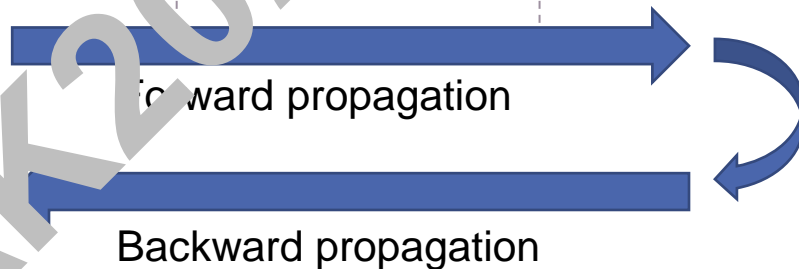


Parameters:

- weight & bias of each node

Hyperparameters (parameters that control parameters):

- # of hidden layers, # of nodes at each layer
- choice of activation function
- learning rate
- # of epoch



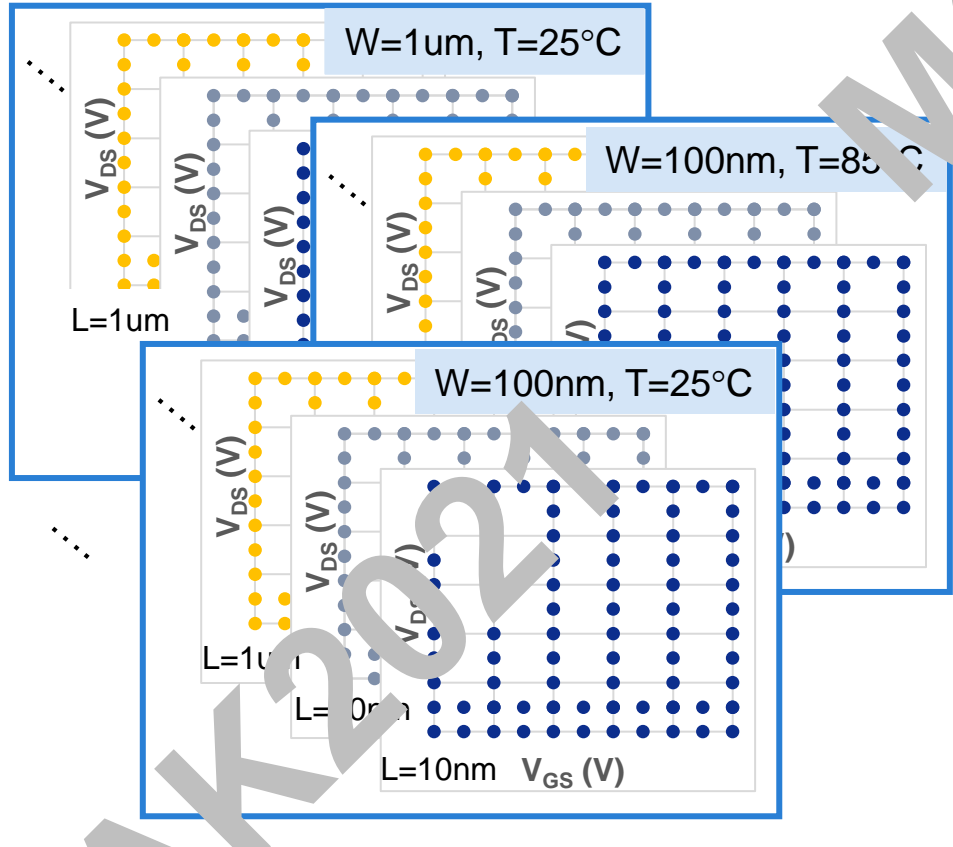
1 epoch: 1 forward & backward propagation for all data

Data-based neural network device model

Example case

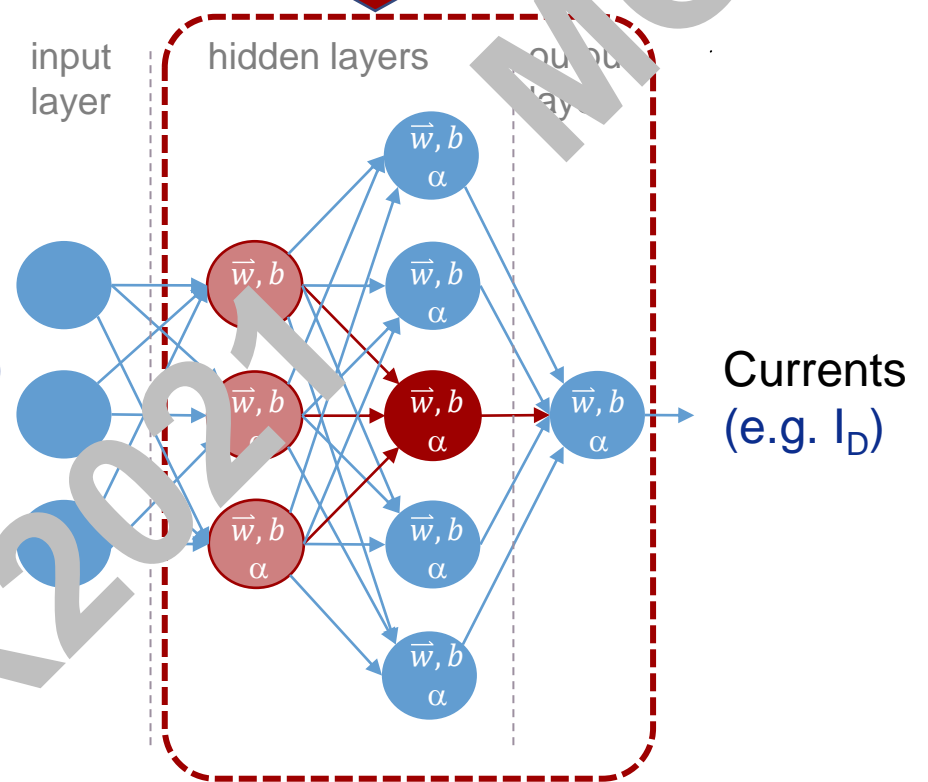
Goal: Generate device model for transistors for any $\{W, L, T\}$

Available measured data:
I-V data for x different combinations
of $\{W, L, T\}$



Voltages
(e.g. V_{GS} , V_{DS})
Parameters
(e.g. W , L , T)

~~Analytical equation~~



Neural compact model

Fixed NN trained with
measured data

W : channel width
 L : channel length
 T : temperature

Outline

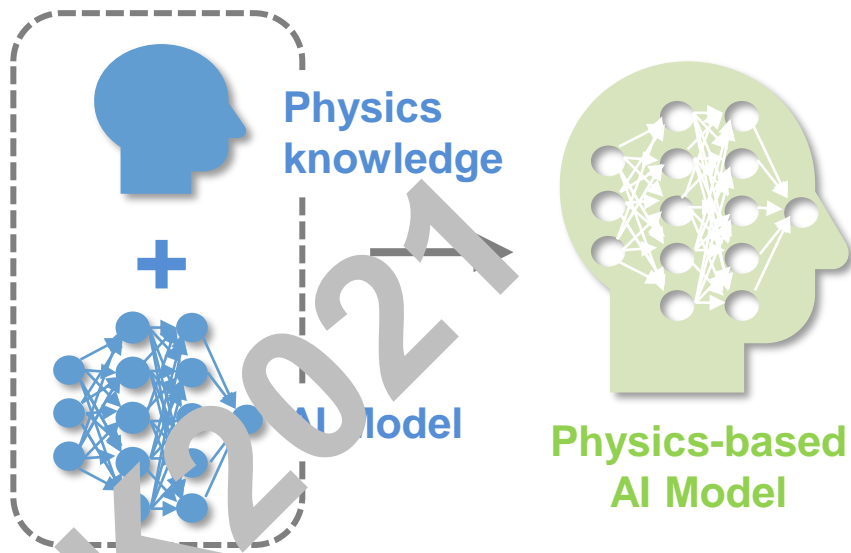
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- **Knowledge-based NN model**
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Simple data-based regression is not sufficient

- Can violate the laws of physics

→ Train with inductive bias

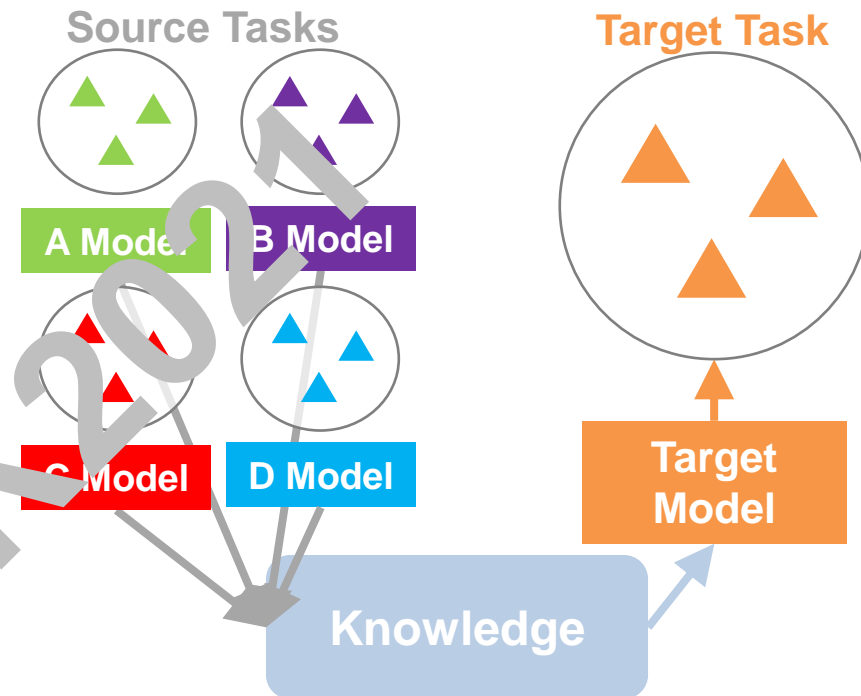
- Domain knowledge based constraints
- Physics-based NN



- Amount of data may not be sufficient

→ Build prior knowledge from multiple tasks

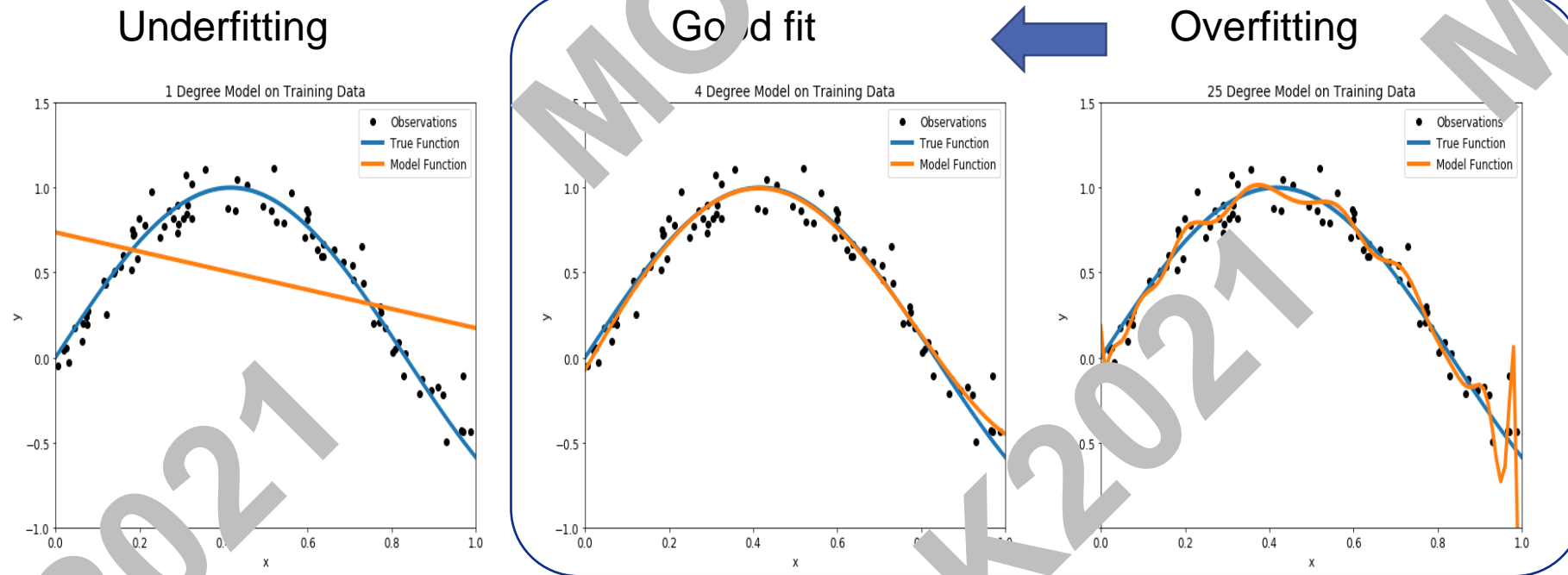
- Multi-task learning
- Meta learning



Domain knowledge based constraints - Concept

- Reduce degree of freedom by incorporating human-knowledge of the domain

Add constraints to avoid overfitting (regularization)



[<https://towardsdatascience.com/overfitting-vs-underfitting-a-complex-example-d05dd7e19765>]

Domain knowledge based constraints - Device example

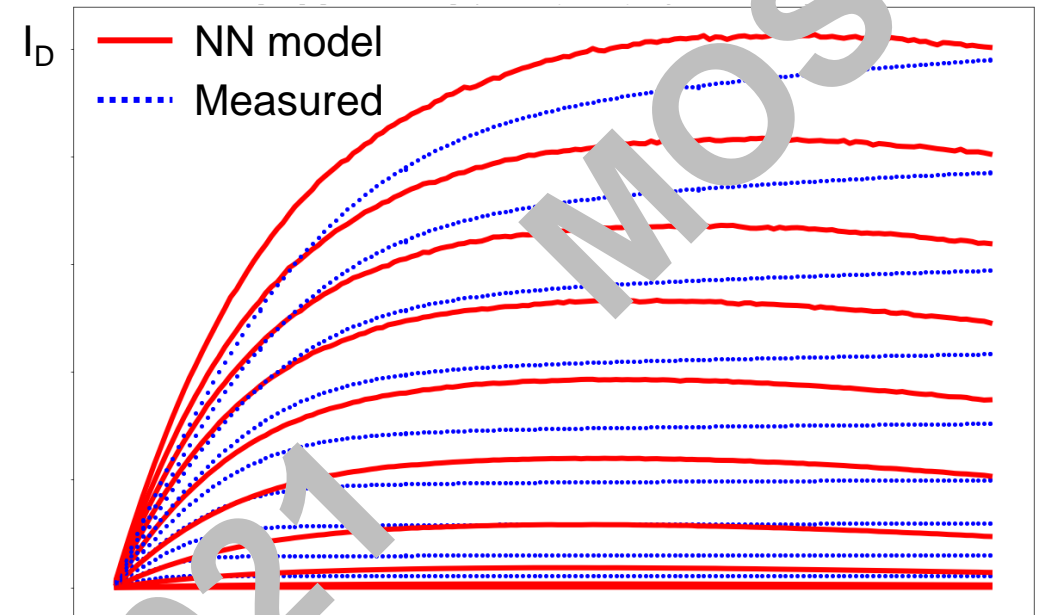
■ Monotonicity

- Knowledge: Increasing voltage increases current
- Constraint: Additional term in cost function that increases when increasing voltage decreases current

■ Smoothness

- Knowledge: Increasing voltage increases current smoothly
- Constraint: Additional term in cost function that increases when I-V curve is not smooth

w/out domain knowledge based constraints



Non monotonic
Not smooth

→ **Not physical!**

V_{DS}

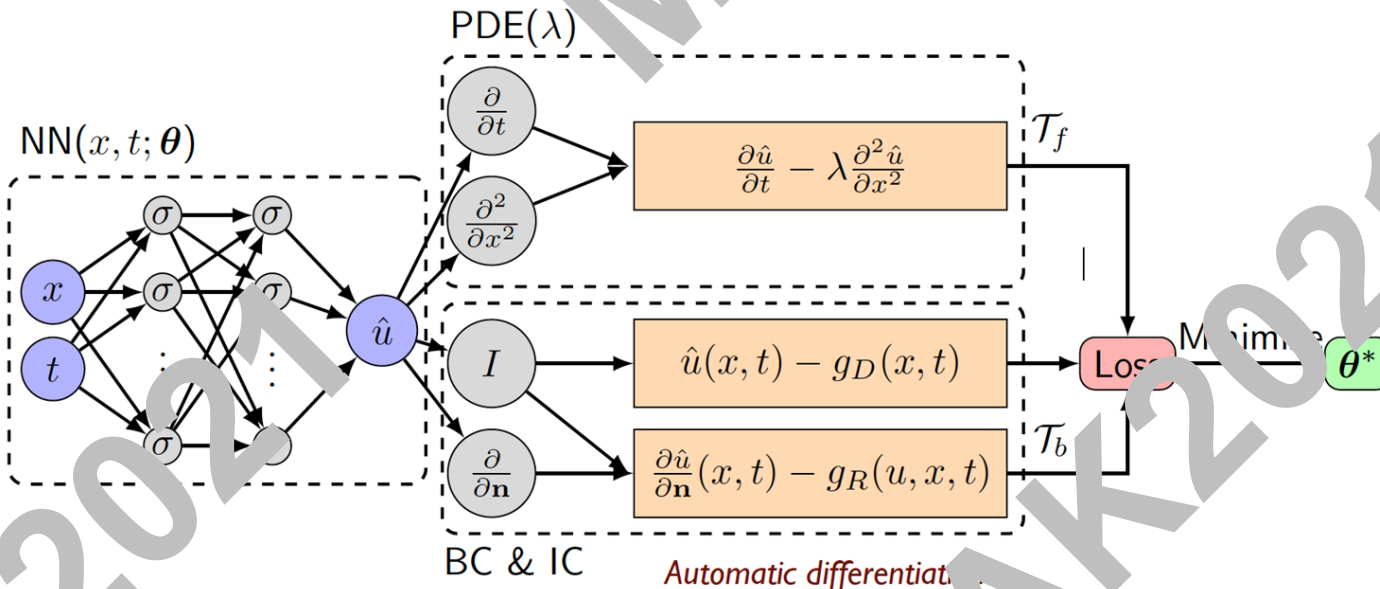
Physics-based NN – Concept

- Modify NN training scheme or architecture by incorporating underlying physics

Example

Train NN so that governing PDE, boundary condition, and initial condition is satisfied

Physics-Informed Neural Network (PINN)

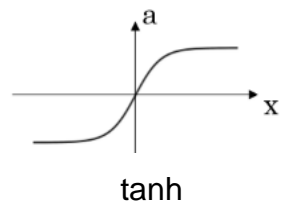
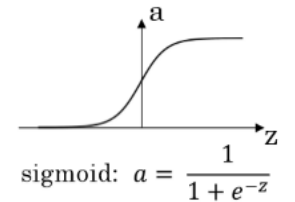
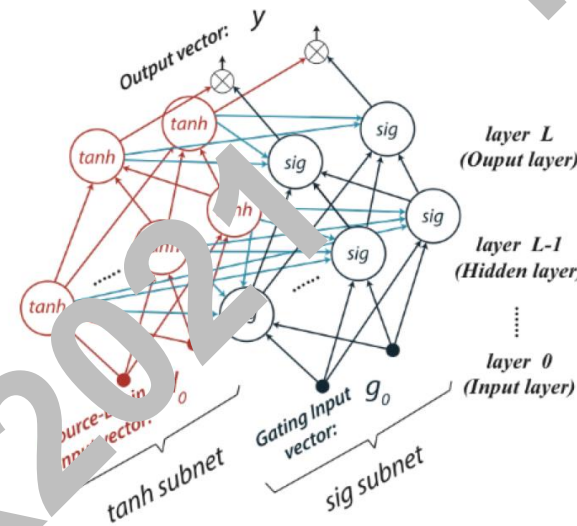
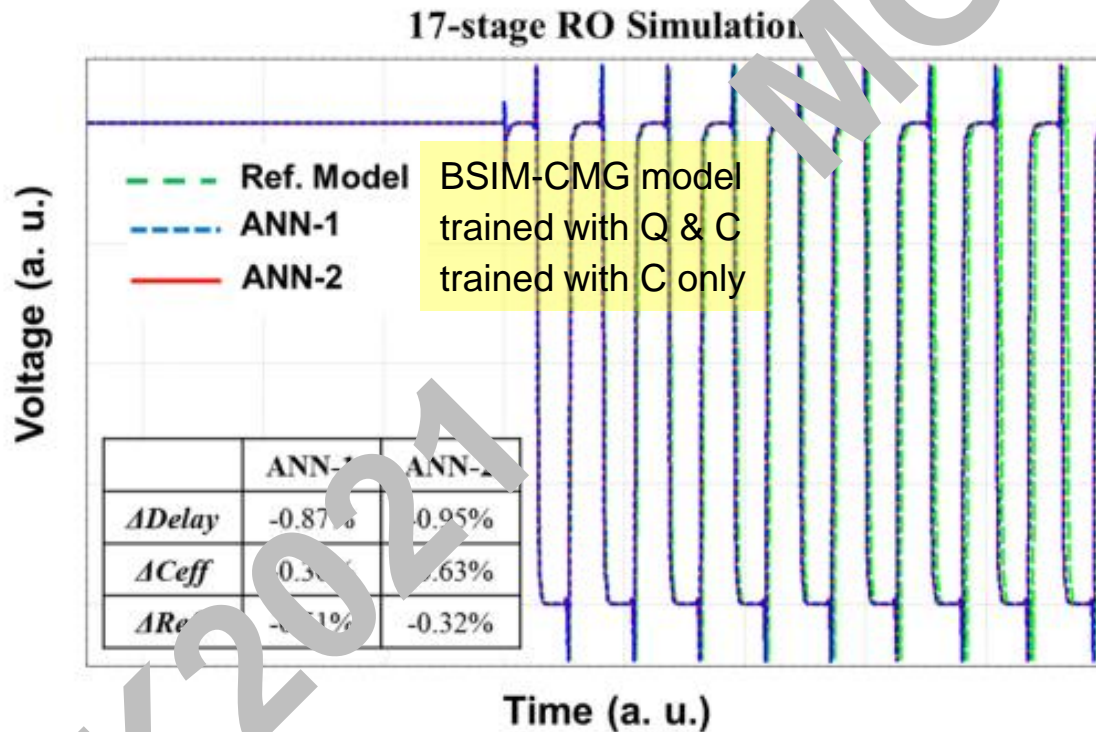


[Lu et al., "DeepXDE: A deep learning library for solving differential equations," *SIAM Rev.*, 2021]

Physics-based NN – Device example

- For modeling Q, use loss function to fit only C (data more readily available than Q)
 - Use knowledge that for simulations, although Q is needed, C ($=dQ/dV$) is what matters

- Select activation functions for NN considering known I-V behavior
 - Choose tanh for V_{DS} input branches ($I_D=0 @ V_{DS}=0$) and sigmoid for V_{GS} input branches ($I_D=0 @ V_{GS}=0$)

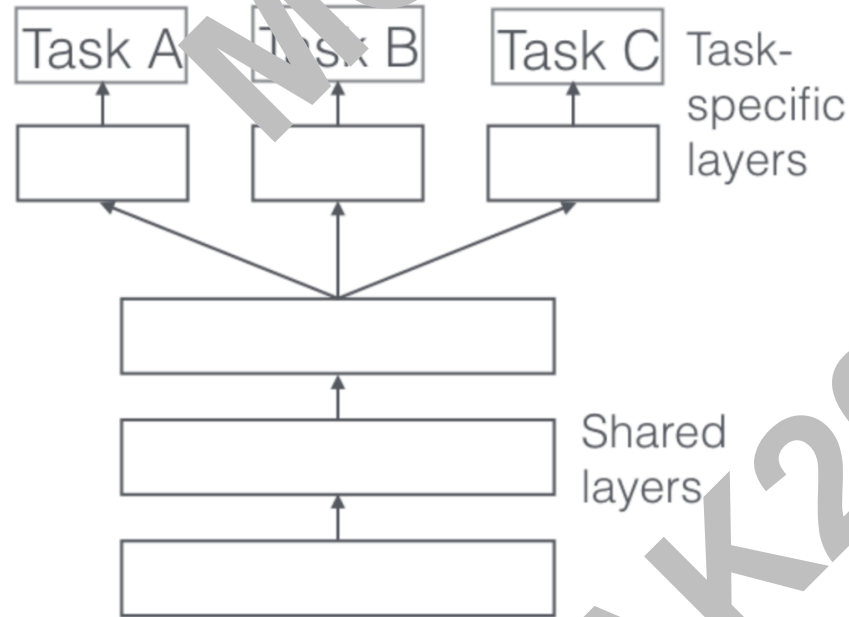


[J. Wang et al., "Artificial neural network-based compact modeling methodology for advanced transistors," TED, 2021]

[M. Li et al., "Physics-inspired neural networks for efficient device compact modeling," *IEEE J. Explor. Solid-State Comput. Devices Circuits*, 2016]

Multi-task learning – Concept

- Learn generalized representation by training with related tasks simultaneously
 - Shared layers with general properties + task-specific layers

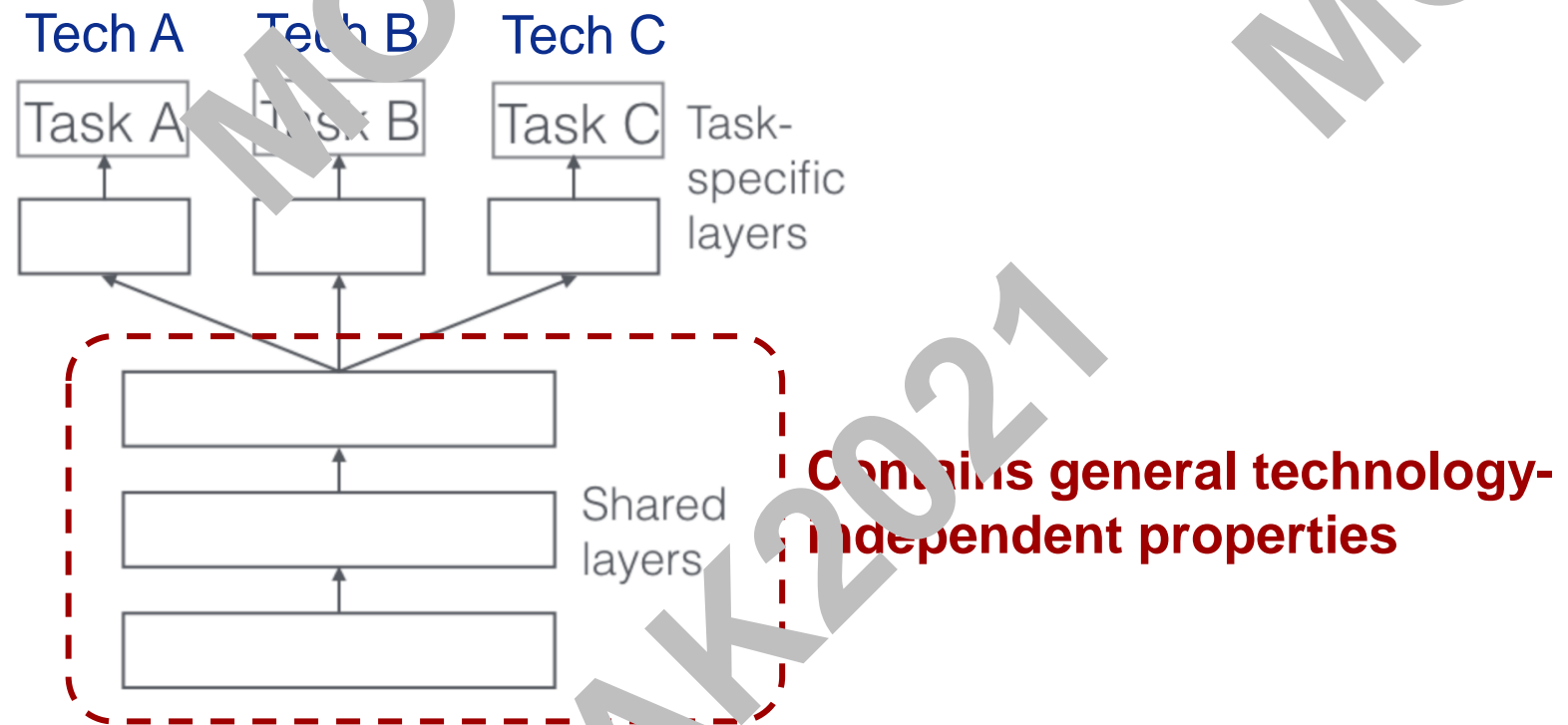


[S. Ruder, "An Overview of Multi-Task Learning in Deep Neural Networks," arXiv:1706.05098v1 [cs.LG]]

Multi-task learning – Device example

Example case:

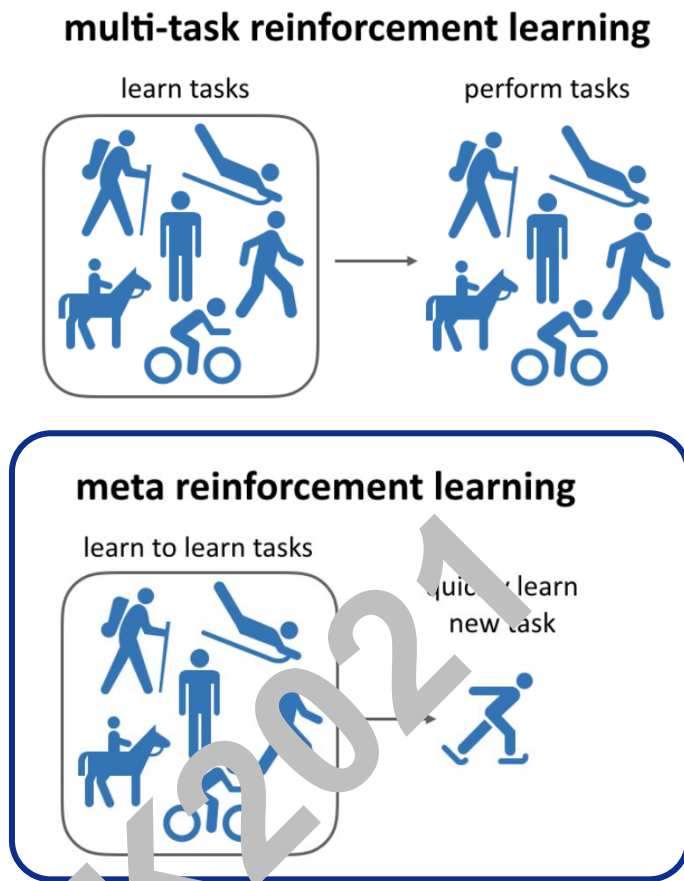
- Goal – Generate device model for transistors for any $\{W, L, T\}$ fabricated with technology A
- Available measured data:
 - I-V data for x different combinations of $\{W, L, T\}$ with technologies A, B, C



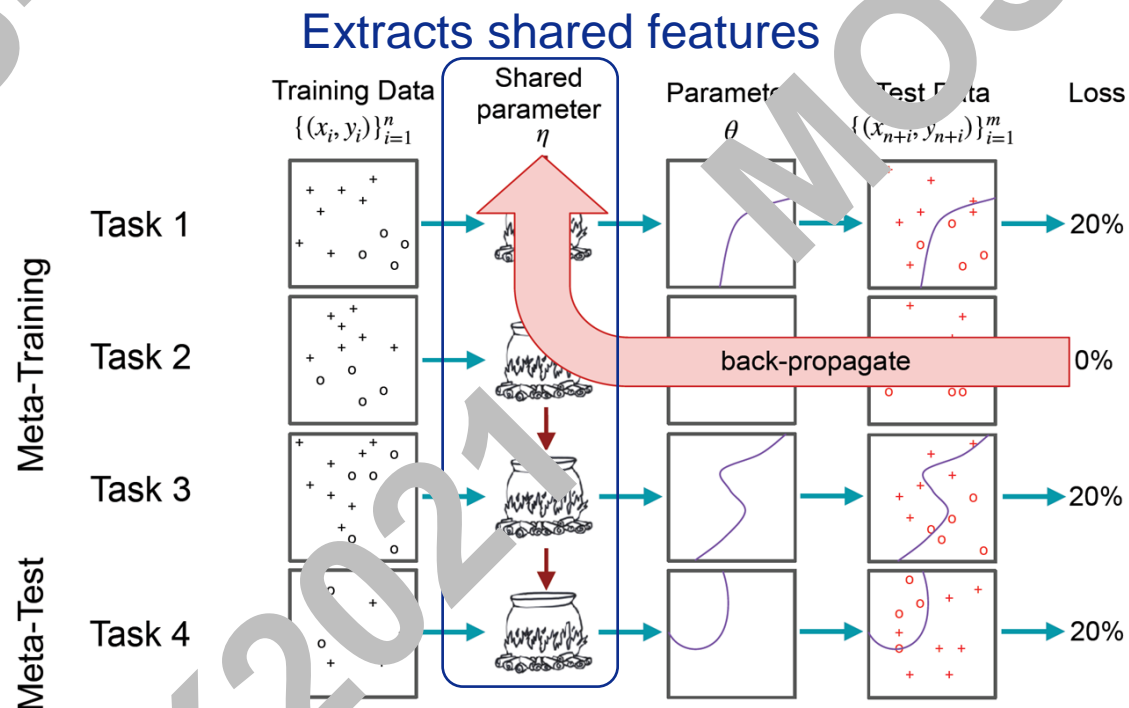
[S. Ruder, "An Overview of Multi-Task Learning in Deep Neural Networks," arXiv:1706.05098v1 [cs.LG]]

Meta learning – Concept

- Extract prior knowledge by “learning to learn” by training with numerous related tasks



<https://meta-world.github.io/>



[X. W. Zeng, "Meta-Learning – an idiosyncratic tutorial, MLSS, 2020]

1. Case-learning: Solves individual tasks
2. Meta-learning: Individual tasks updated to improve generalization performance

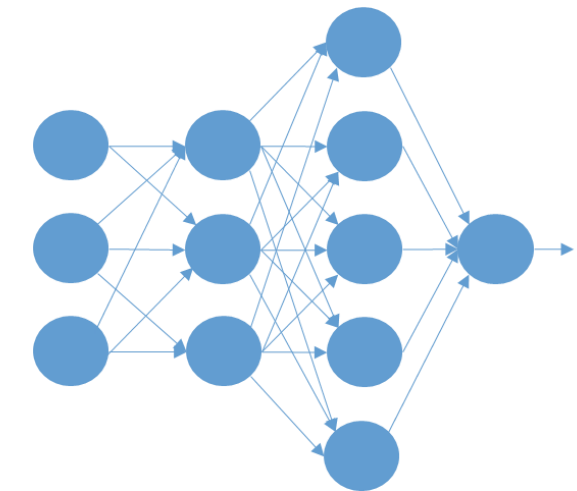
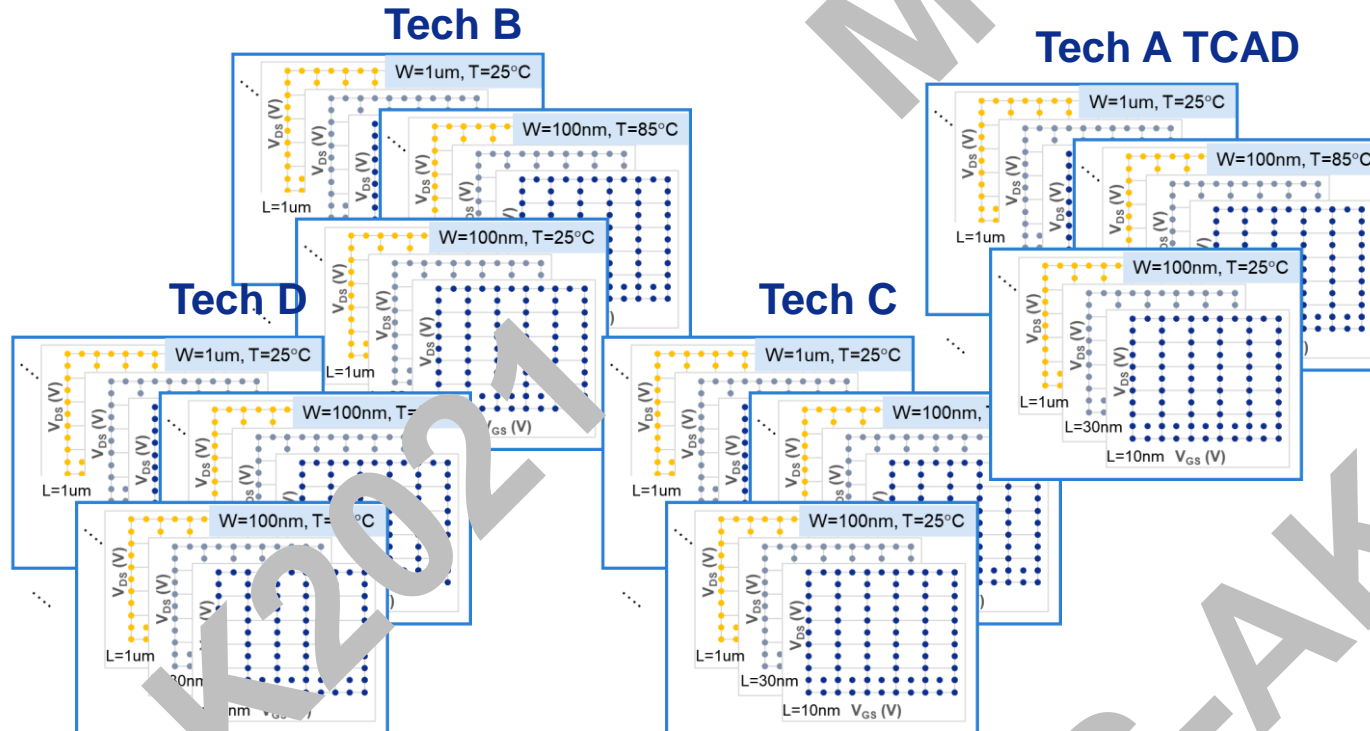
Meta learning – Device example

Example case:

- Goal – Generate device model for transistors for any $\{W, L, T\}$ fabricated with technology A
- Available measured data:
 - I-V data for x different combinations of $\{W, L, T\}$ with technologies A, B, C, D, ...

Learn to learn tasks w/ other technology data and/or TCAD data

Quickly learn tech A



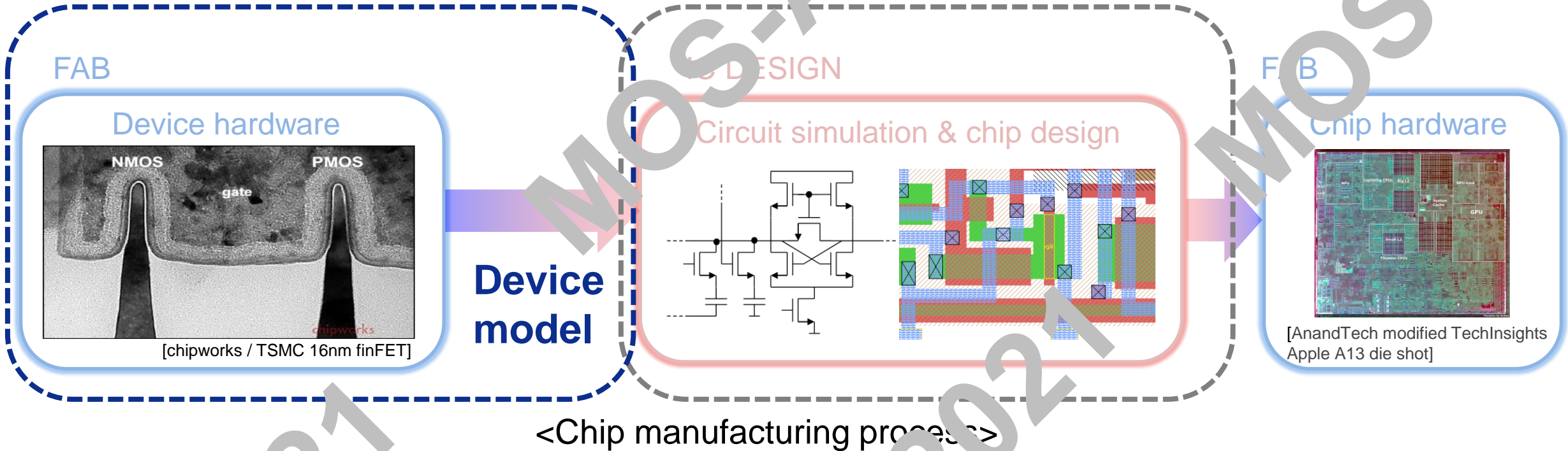
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End-to-end autonomous technology development

New EDA market

Focus of conventional EDA market



Full automation from device design to chip design

- A new paradigm in the global semiconductor industry

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Thank you

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